

# GTVA262701FA

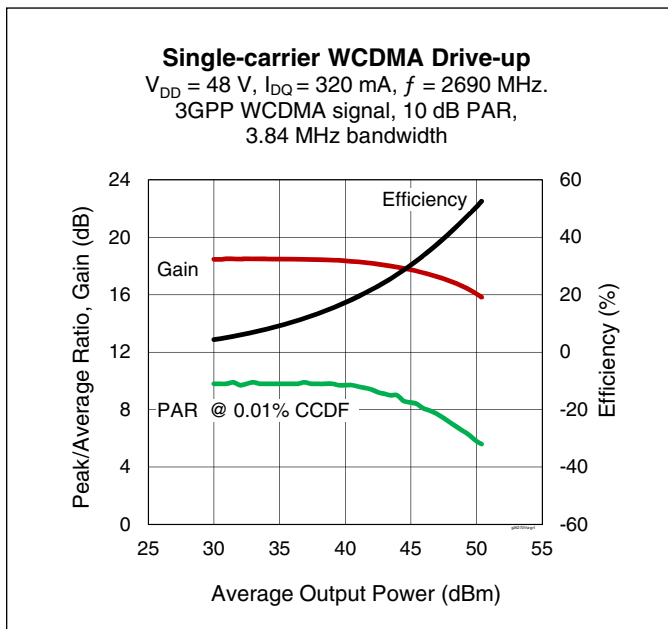
Thermally-Enhanced High Power RF GaN on SiC HEMT  
270 W, 48 V, 2620 – 2690 MHz



Package Types: H-87265J-2

## Description

The GTVA262701FA is a 270-watt GaN on SiC high electron mobility transistor (HEMT) for use in multi-standard cellular power amplifier applications. It features input matching, high efficiency, and a thermally-enhanced surface-mount package with earless flange.



## Features

- GaN on SiC HEMT technology
- Input matched
- Typical pulsed CW performance: 10  $\mu\text{s}$  pulse width, 10% duty cycle, 2690 MHz, 48 V
  - Output power at  $P_{3\text{dB}} = 270\text{ W}$
  - Efficiency = 66%
  - Gain = 18.1 dB
- Human Body Model Class 1B (per ANSI/ESDA/ JEDEC JS-001)
- Capable of handling 10:1 VSWR @48 V, 60 W (WCDMA) output power
- Pb-free and RoHS compliant

## RF Characteristics

### Single-carrier WCDMA Specifications (tested in the production test fixture)

$V_{DD} = 48\text{ V}$ ,  $I_{DQ} = 320\text{ mA}$ ,  $P_{OUT} = 60\text{ W avg}$ ,  $f = 2690\text{ MHz}$ , 3GPP signal, channel bandwidth = 3.84 MHz, peak/average = 10 dB @ 0.01% CCDF

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Gain	$G_{ps}$	16.5	17	—	dB
Drain Efficiency	$\eta_D$	40	42	—	%
Adjacent Channel Power Ratio	ACPR	—	-28	-27	dBc
Output PAR @ 0.01% CCDF	OPAR	5.5	6.2	—	dB

Note:

All published data at  $T_{CASE} = 25^\circ\text{C}$  unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!



## DC Characteristics

Characteristic	Symbol	Min.	Typ.	Max.	Unit	Conditions
Drain-source Breakdown Voltage	$V_{BR(DSS)}$	150	—	—	V	$V_{GS} = -8\text{ V}, I_D = 10\text{ mA}$
Drain-source Leakage Current	$I_{DSS}$	—	—	4.5	mA	$V_{GS} = -8\text{ V}, V_{DS} = 10\text{ V}$
Gate Threshold Voltage	$V_{DSX(th)}$	-3.8	-3.0	-2.3	V	$V_{DS} = 10\text{ V}, I_D = 32\text{ mA}$

## Recommended Operating Conditions

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Operating Voltage	$V_{DD}$	0	—	50	V	
Gate Quiescent Voltage	$V_{GS(Q)}$	—	-3.0	—		$V_{DS} = 50\text{ V}, I_D = 320\text{ mA}$

## Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source Voltage	$V_{DSS}$	125	V
Gate-Source Voltage	$V_{GS}$	-10 to +2	
Gate Current	$I_G$	32	mA
Drain Current	$I_D$	12	A
Junction Temperature	$T_J$	225	°C
Storage Temperature Range	$T_{STG}$	-65 to +150	

Operation above the maximum values listed here may cause permanent damage. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the component. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. For reliable continuous operation, the device should be operated within the operating voltage range ( $V_{DD}$ ) specified above.

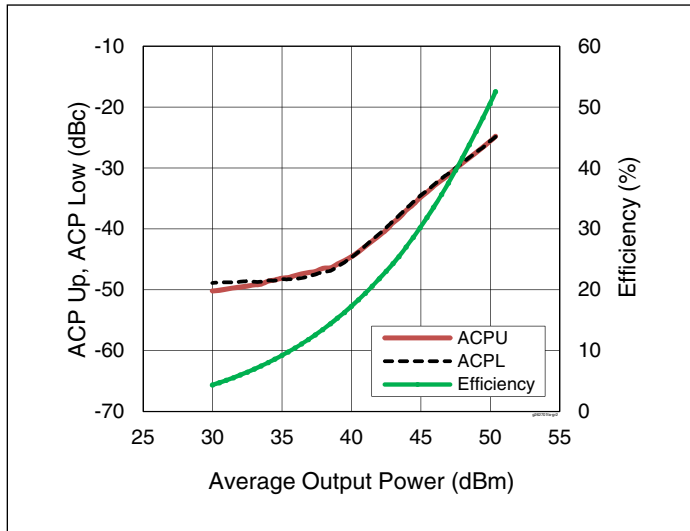
## Thermal Characteristics

Characteristic	Symbol	Value	Unit	Conditions
Thermal Resistance	$R_{\theta JC}$	1.1	°C/W	$T_{CASE} = 70\text{ °C}, 60\text{ W (CW)}, V_{DD} = 48\text{ V}, I_{DQ} = 320\text{ mA}, 2690\text{ MHz}$

## Ordering Information

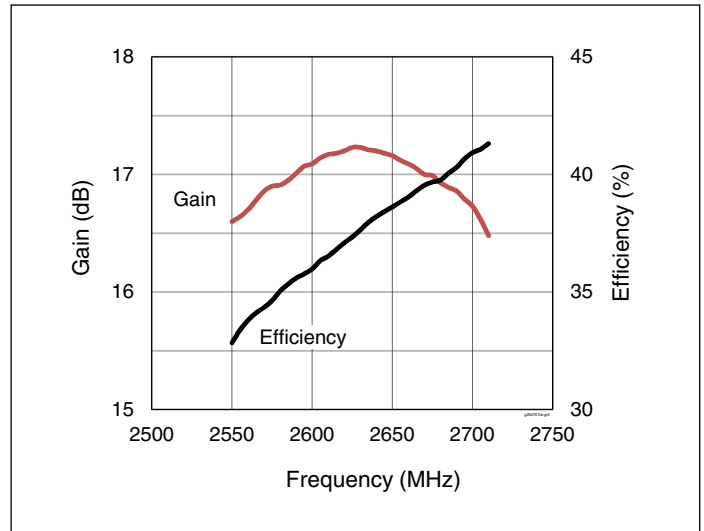
Type and Version	Order Code	Package	Shipping
GTVA262701FA V2 R0	GTVA262701FA-V2-R0	H-87265J-2	Tape & Reel, 50 pcs
GTVA262701FA V2 R2	GTVA262701FA-V2-R2	H-87265J-2	Tape & Reel, 250 pcs

**Typical Performance** (data taken in the production test fixture)



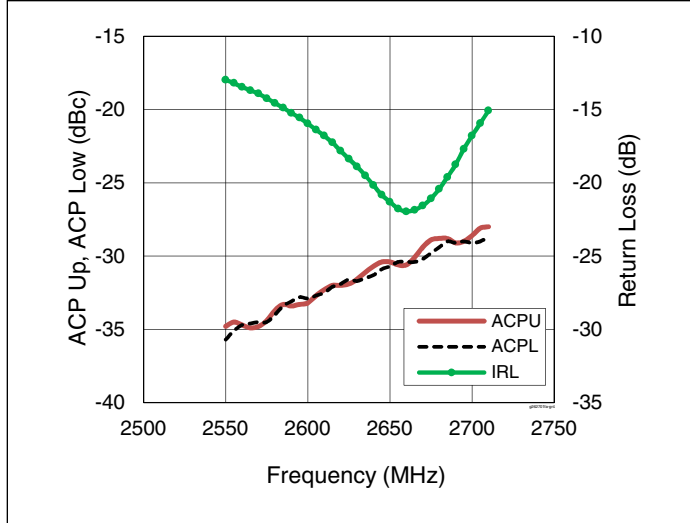
**Figure 1.** Single-carrier WCDMA Drive-up

$V_{DD} = 48\text{ V}$ ,  $I_{DQ} = 320\text{ mA}$ ,  $f = 2690\text{ MHz}$ .  
3GPP WCDMA signal, 10 dB PAR,  
3.84 MHz bandwidth



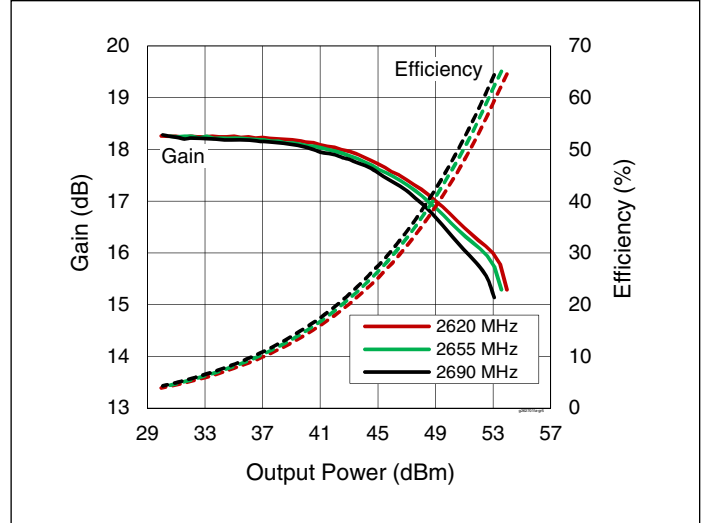
**Figure 2.** Single-carrier WCDMA Broadband

$V_{DD} = 48\text{ V}$ ,  $I_{DQ} = 320\text{ mA}$ ,  $P_{OUT} = 47.78\text{ dBm}$   
3GPP WCDMA signal, 10 dB PAR



**Figure 3.** Single-carrier WCDMA Broadband

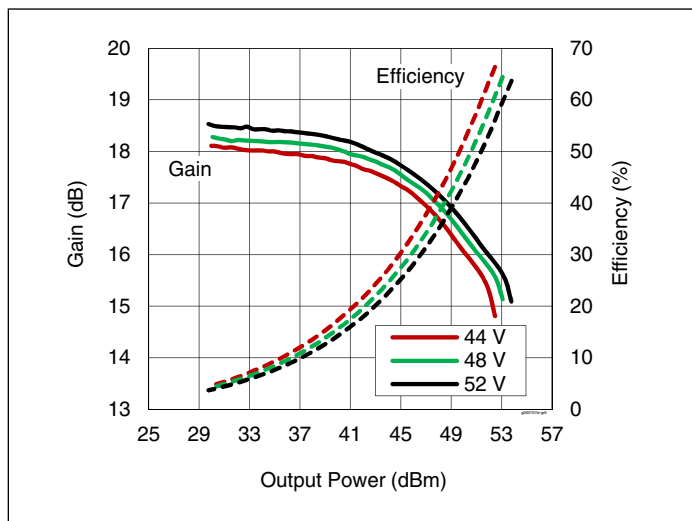
$V_{DD} = 48\text{ V}$ ,  $I_{DQ} = 320\text{ mA}$ ,  $P_{OUT} = 47.78\text{ dBm}$   
3GPP WCDMA signal, 10 dB PAR



**Figure 4.** CW Performance

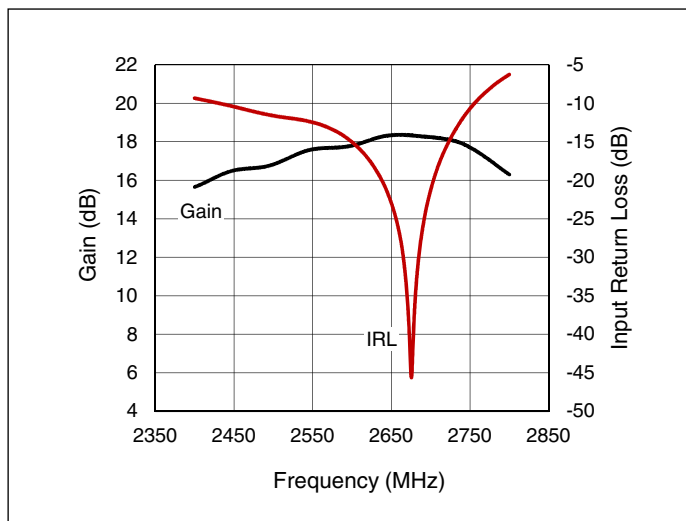
$V_{DD} = 48\text{ V}$ ,  $I_{DQ} = 320\text{ mA}$   
series show frequency

**Typical Performance** (cont.)



**Figure 5.** CW Performance at Selected  $V_{DD}$

$I_{DQ} = 320 \text{ mA}$ ,  $f = 2690 \text{ MHz}$   
series show voltage



**Figure 6.** CW Performance, Small Signal

$V_{DD} = 48 \text{ V}$ ,  $I_{DQ} = 320 \text{ mA}$

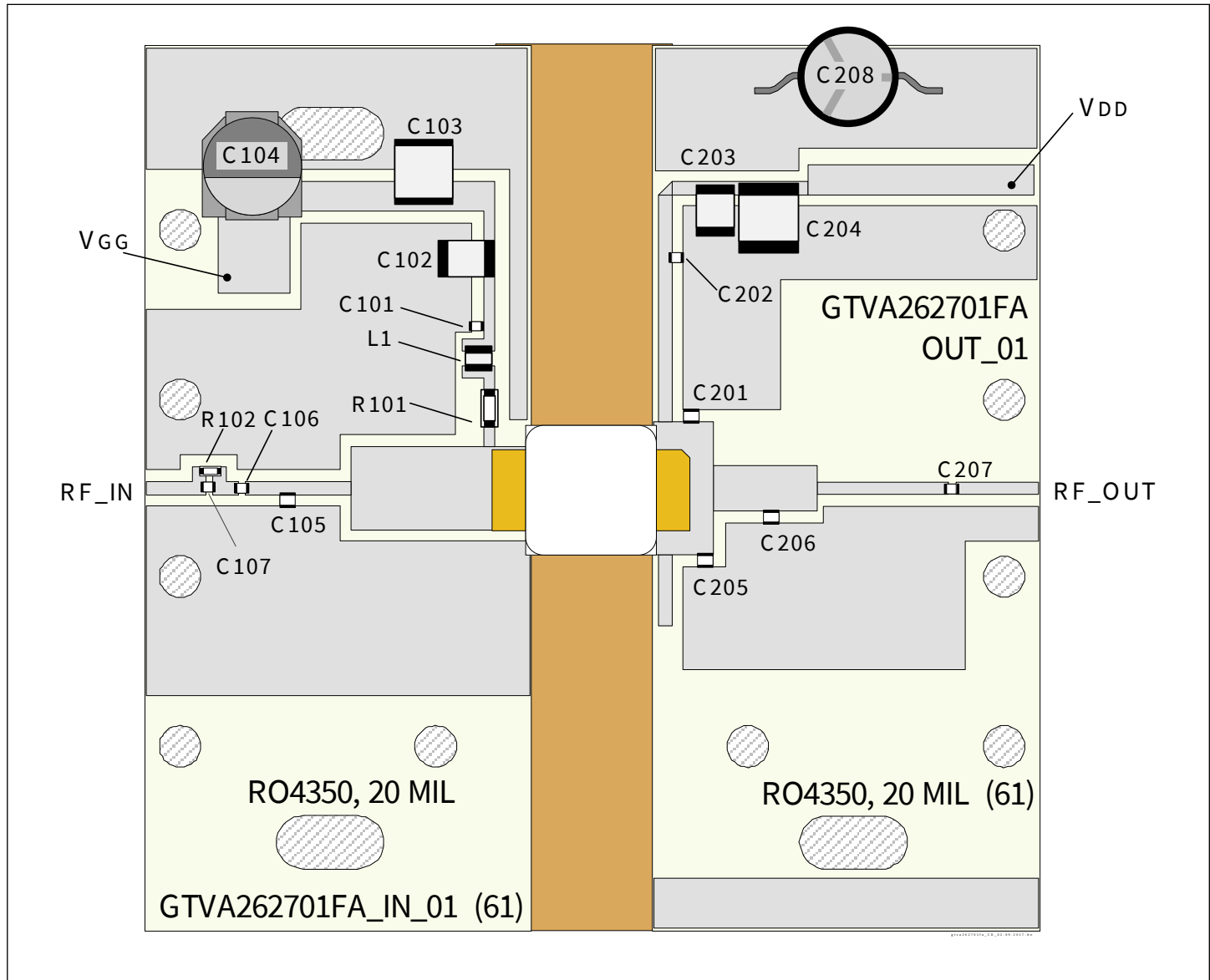
**Load Pull Performance**

**Pulsed CW signal:** - 10  $\mu\text{sec}$ , 10% duty cycle; 48 V, 320 mA

Class AB			$P_{3dB}$										
			Max Output Power					Max Drain Efficiency					
Freq [MHz]	$Z_s [\Omega]$	$Z_{12f0} [\Omega]$	$Z_l [\Omega]$	Gain [dB]	$P_{3dB} [\text{dBm}]$	$P_{3dB} [\text{W}]$	$\eta_D [\%]$	$Z_l [\Omega]$	Gain [dB]	$P_{3dB} [\text{dBm}]$	$P_{3dB} [\text{W}]$	$\eta_D [\%]$	
2620	6.90 - j4.0	1.4 + j4.3	2.24 - j3.80	15.2	54.71	296	62.3	1.95 - j1.91	17.45	52.89	194.5	75.1	
2655	6.85 - j3.4	2.3 + j10	2.20 - j3.78	15.2	54.80	302	63.4	2.26 - j2.27	16.70	53.14	206.1	73.6	
2690	5.90 - j4.8	1.7 + j8.3	2.12 - j3.74	15.2	54.78	301	65.1	1.80 - j2.00	16.80	52.65	184.1	75.7	

## Evaluation Board, 2620 to 2690 MHz

Evaluation Board Part Number	LTN/GTVA262701FA-V2
PCB Information	Rogers 4350, 0.508 mm [0.020"] thick, 2 oz. copper, $\epsilon_r = 3.66$



## Components Information

Component	Description	Manufacturer	P/N
<b>Input</b>			
C101	Capacitor, 33 pF	ATC	ATC800A330JT250T
C102	Capacitor, 1 $\mu$ F	TDK Corporation	C4532X7R2A105M230KA
C103	Capacitor, 10 $\mu$ F	TDK Corporation	C5750X5R1H106K230KA
C104	Capacitor, 100 $\mu$ F	Panasonic Electronic Components	EEV-HD1V101P
C105	Capacitor, 1.8 pF	ATC	ATC800A1R8CT250T
C106, C107	Capacitor, 12 pF	ATC	ATC800A120JT250T
L1	Inductor, 22 nH	ATC	0805WL220JT
R101	Resistor, 5.6 ohms	Panasonic Electronic Components	ERJ-8RQJ5R6V
R102	Resistor, 10 ohms	Panasonic Electronic Components	ERJ-3GEYJ100V
<b>Output</b>			
C201	Capacitor, 1.1 pF	ATC	ATC800A1R1CT250T
C202, C207	Capacitor, 12 pF	ATC	ATC800A120JT250T
C203	Capacitor, 1 $\mu$ F	TDK Corporation	C4532X7R2A105M230KA
C204	Capacitor, 10 $\mu$ F	TDK Corporation	C5750X5R1H106K230KA
C205	Capacitor, 0.9 pF	ATC	ATC800A0R9CT250T
C206	Capacitor, 0.4 pF	ATC	ATC800A0R4CT250T
C208	Capacitor, 220 $\mu$ F	Panasonic Electronic Components	ECA-2AHG221

## Bias Sequencing

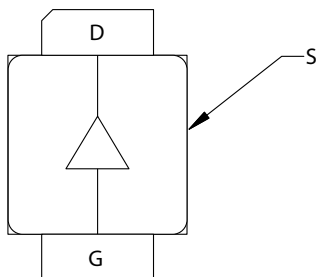
### Bias On

1. Ensure RF is turned off
2. Apply pinch-off voltage of  $-5$  V to the gate
3. Apply nominal drain voltage
4. Bias gate to desired quiescent drain current
5. Apply RF

### Bias Off

1. Turn RF off
2. Apply pinch-off voltage to the gate
3. Turn-off drain voltage
4. Turn-off gate voltage

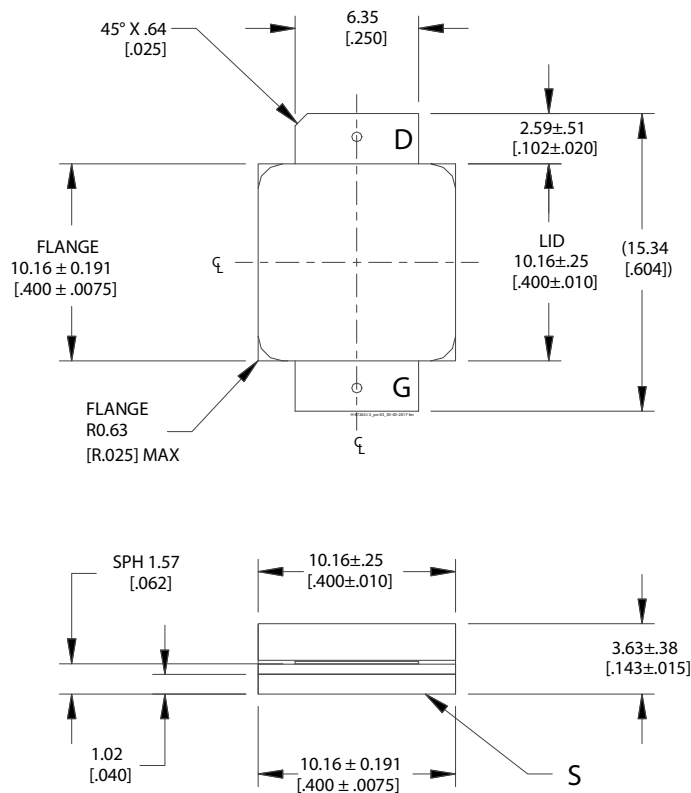
## Pinout Diagram (top view)



Pin	Description
D	Drain
G	Gate
S	Source (flange)

Lead connections for GTVA262701FA

## Package Outline Specifications – Package H-87265J-2



### Diagram Notes—unless otherwise specified:

1. Interpret dimensions and tolerances per ASME Y14.5M-1994.
2. Primary dimensions are mm. Alternate dimensions are inches.
3. All tolerances  $\pm 0.127$  [.005] unless specified otherwise.
4. Pins: D – drain; G – gate; S – source.
5. Lead thickness:  $0.13 \pm 0.05$  mm [ $.005 \pm .002$  inch].
6. Gold plating thickness:  $1.14 \pm 0.38$  micron [ $45 \pm 15$  microinch].

## Notes & Disclaimer

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